



30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

-41 A

Features

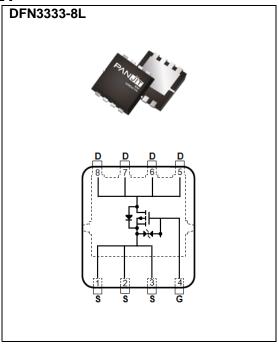
- RDS(ON), VGS@-10V, ID@-10A<15.4m Ω
- RDS(ON), VGS@-4.5V, ID@-6A<27m Ω
- 100% UIS tested
- Reliable and Rugged
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-30	V	
Gate-Source Voltage		V _{GS}	±25	\ \ \	
Continuous Drain Current(Note 3)	T _C =25°C	l _D	-41	А	
	T _C =100°C		-29		
Pulsed Drain Current(Note 1)	T _C =25°C	I _{DM}	-123		
Power Dissipation	T _C =25°C	Po	41	10/	
	T _C =100°C		20	W	
Continuous Drain Current(Note 4)	T _A =25°C	I _D	-10		
	T _A =70°C		-8.4	A	
Power Dissipation	T _A =25°C	ר	2.5	W	
	T _A =70°C	Po	1.8		
Single Pulse Avalanche Energy ^(Note 5)		Eas	49	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~175	°C	
Thermal Resistance ^(Note 4)	Junction to Case	R _{θJC}	3.7	°C/W	
	Junction to Ambient	$R_{\theta JA}$	60		





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static	•						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-		
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.8	-2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-10A	-	12.3	15.4	mΩ	
		V _{GS} =-4.5V, I _D =-6A	-	20.8	27		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1	uA	
Onto Course London Course		V _{GS} =±25V, V _{DS} =0V	-	-	±10	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±10V, V _{DS} =0V	-	-	±1		
Dynamic ^(Note 6)		,					
Total Gate Charge	Qg	V 04V L 40A	-	32	-	nC	
Gate-Source Charge	Qgs	V _{DS} =-24V, I _D =-10A,	-	5	-		
Gate-Drain Charge	Q_{gd}	VGS=-10V	-	10	-		
Input Capacitance	Ciss	V 05)/ V 0)/	-	1270	-	pF	
Output Capacitance	Coss	V _{DS} =-25V, V _{GS} =0V, f=1MHz	-	190	-		
Reverse Transfer Capacitance	Crss	I=IIVIHZ	-	170	-		
Gate resistance	Rg	f=1MHz	-	7	-	Ω	
Turn-On Delay Time	td _(on)	\/ O4\/ 40A	-	7	-	ns	
Turn-On Rise Time	tr	V _{DS} =-24V, I _D =-10A,	-	9	-		
Turn-Off Delay Time	td _(off)	V _{GS} =-10V, R _G =3 Ω	-	32	-		
Turn-Off Fall Time	tf	(11010 2)	-	39	-		
Drain-Source Diode			_				
Diode Forward Current	Is	Tc=25°C	-	-	-41	А	
Pulsed Diode Forward Voltage	I _{SM}	1C=25 C	-	-	-123		
Diode Forward Voltage	V _{SD}	I _S =-20A, V _{GS} =0V	-	-0.9	-1.3	V	
Reverse Recovery Time	Trr	V _{GS} =0V, I _S =-20A	-	18	-	ns	
Reverse Recovery Charge	Qrr	dls/dt=100A/us	-	8	-	nC	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS} =-14A, V_{DD} =-30V, V_{GS} =-10V, Starting T_{J} =25°C.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

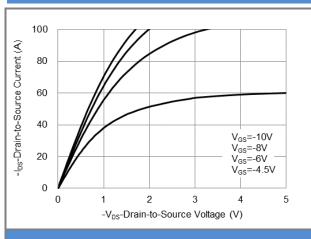


Fig.1 On-Region Characteristics

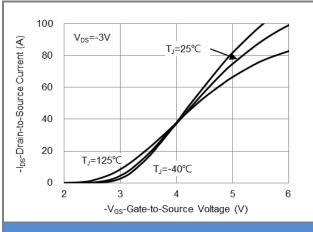


Fig.2 Transfer Characteristics

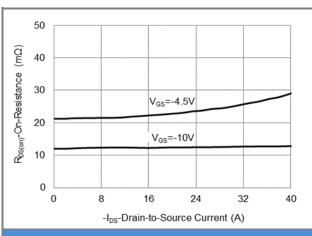


Fig.3 On-Resistance vs. Drain Current

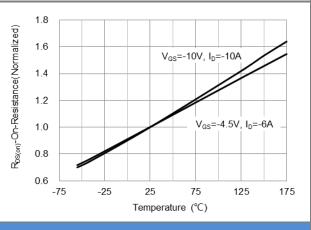
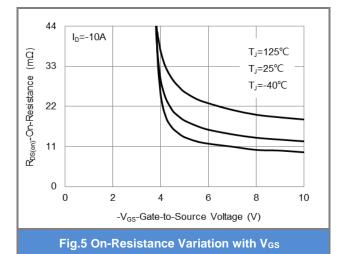


Fig.4 On-Resistance vs. Junction temperature



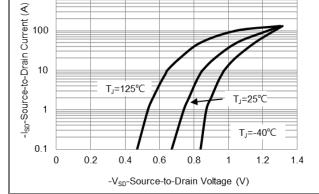


Fig.6 Source-Drain Diode Forward Voltage

1000





TYPICAL CHARACTERISTIC CURVES

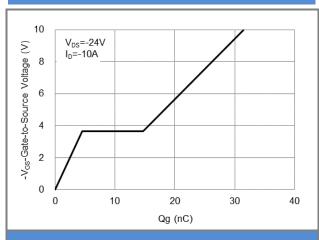


Fig.7 Gate-Charge Characteristics

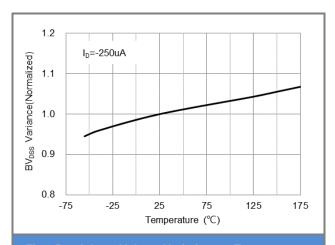


Fig.8 Breakdown Voltage Variation vs. Temperature

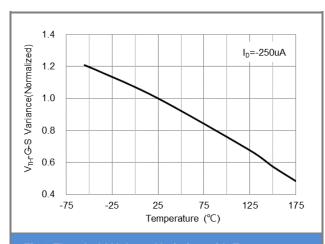


Fig.9 Threshold Voltage Variation with Temperature

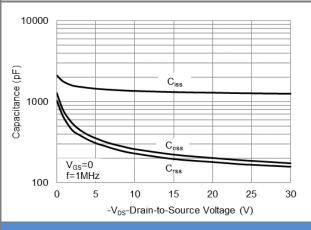


Fig.10 Capacitance vs. Drain-Source Voltage

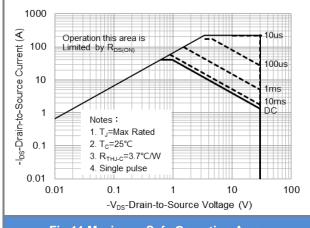


Fig.11 Maximum Safe Operating Area

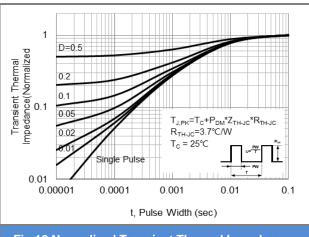


Fig.12 Normalized Transient Thermal Impedance

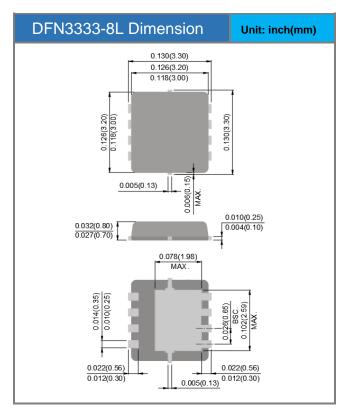


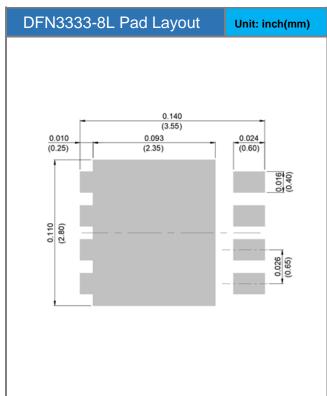


Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJQ4437EP-AU	DFN3333-8L	5K pcs / 13" reel	437E	

Packaging Information & Mounting Pad Layout









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